

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP665G

OFFICE MACHINE

HOUSEHOLD USE EQUIPMENT

TRIAC DRIVER

SOLID STATE RELAY

The TOSHIBA TLP665G consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

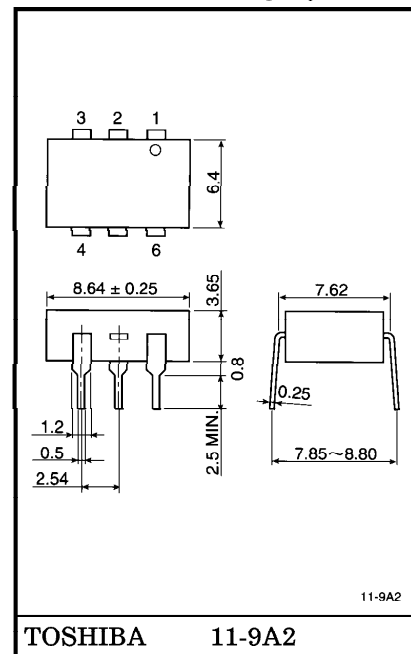
- Peak Off-State Voltage : 400V (Min.)
- Trigger LED Current : 10mA (Max.)
- On-State Current : 100mA (Max.)
- UL Recognized : UL1577, File No. E67349
- Isolation Voltage : 5000V_{rms} (Min.)
- Option (D4) type
VDE Approved : DIN VDE0884 /08.87,
Certificate No. 68383
Maximum Operating Insulation Voltage : 630V_{PK}
Highest Permissible Over Voltage : 6000V_{PK}

(Note) When a VDE0884 approved type is needed, please designate the "Option (D4)"

- Structural Parameter

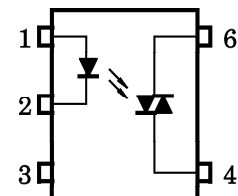
	7.62mm pitch standard type
Creepage Distance	7.0mm (Min.)
Clearance	7.0mm (Min.)
Insulation Thickness	0.5mm (Min.)

Unit in mm



Weight : 0.44g

PIN CONFIGURATION (TOP VIEW)



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MAXIMUM RATINGS (Ta = 25°C)

LED	Forward Current	I _F	50	mA
	Forward Current Derating (Ta ≤ 53°C)	ΔI _F / °C	−0.7	mA / °C
	Peak Forward Current (100μs pulse, 100pps)	I _{FP}	1	A
	Reverse Voltage	V _R	5	V
	Junction Temperature	T _j	125	°C
DETECTOR	Off-State Output Terminal Voltage	V _{DRM}	400	V
	On-State RMS Current	I _T (RMS)	100	mA
			50	
	On-State Current Derating (Ta ≥ 25°C)	ΔI _T / °C	−1.1	mA / °C
	Peak On-State Current (100μs pulse, 120pps)	I _{TP}	2	A
	Peak Nonrepetitive Surge Current (P _W = 10ms, DC = 10%)	I _{TSM}	1.2	A
	Junction Temperature	T _j	115	°C
Storage Temperature Range		T _{stg}	−55~125	°C
Operating Temperature Range		T _{opr}	−40~100	°C
Lead Soldering Temperature (10s)		T _{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)		BVS	5000	V _{rms}

(Note 1) Device considered a two terminal device : Pins 1, 2 and 3 shorted together pin 4 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{AC}	—	—	120	V _{ac}
Forward Current	I _F	15	20	25	mA
Peak On-Stage Current	I _{TP}	—	—	1	A
Operating Temperature	T _{opr}	−25	—	85	°C

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Peak Off-State Current	I_{DRM}	$V_{\text{DRM}} = 400\text{V}$	—	10	100	nA
	Peak On-State Voltage	V_{TM}	$I_{\text{TM}} = 100\text{mA}$	—	1.7	3.0	V
	Holding Current	I_H	—	—	0.6	—	mA
	Critical Rate of Rise of Off-State Voltage	dv/dt	$V_{\text{in}} = 120\text{V}, T_a = 85^\circ\text{C}$ (Note 2)	200	500	—	$\text{V} / \mu\text{s}$
	Critical Rate of Rise of Commutating Voltage	$dv/dt(c)$	$V_{\text{in}} = 30\text{V}_{\text{rms}}, I_T = 15\text{mA}$ (Note 2)	—	0.2	—	$\text{V} / \mu\text{s}$

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$V_T = 3\text{V}$	—	5	10	mA
Capacitance (Input to Output)	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	5000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

(Note 2) dv/dt TEST CIRCUIT

